



**THE DATASHEET OF  
ZDS1009TA**



## SM-8 COMPLEMENTARY CURRENT MIRROR

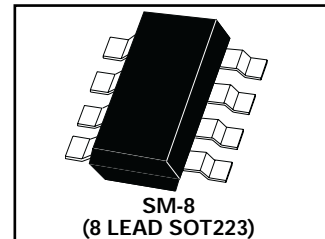
### DESCRIPTION

The ZDS1009 current mirror has been developed specifically for high side, current sense plus level translation applications and as such will find a broad application base including battery charge management, DC motor control and over current monitoring functions. It is of particular interest for current sense applications for feedback purposes in fast battery chargers for Li-Ion cell based systems.

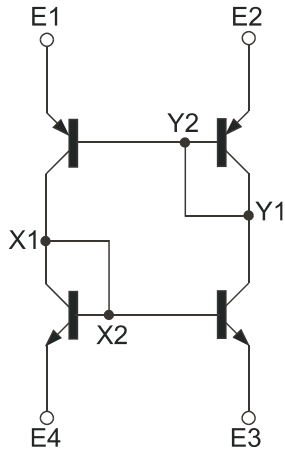
The device functions by sensing the voltage developed across an external (user defined) high side current sense resistor, and by an arrangement of current mirrors refer this sensed voltage, with or without multiplication, to a low side referenced signal. This signal can then be used, for example, to close the control loop to a controller IC, for a DC-DC converter providing charge to a battery.

### FEATURES

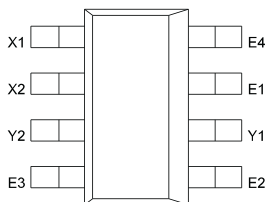
- Excellent Temperature Tracking Characteristics
- Compact Cost Effective Solution
- Simplifies Circuit Implementation
- Broad application base from Single Cell Li-ion High Side Current sense chargers to Multi-cell Lead-Acid systems
- Only 4 Connections required



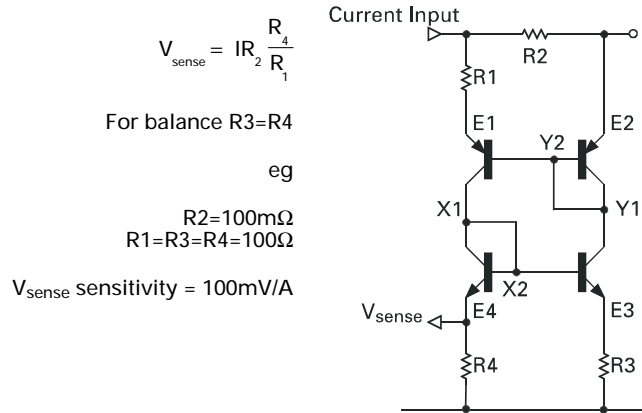
### SCHEMATIC DIAGRAM



### CONNECTION DIAGRAM



### TYPICAL APPLICATION CIRCUIT



# ZDS1009

## ABSOLUTE MAXIMUM RATINGS.

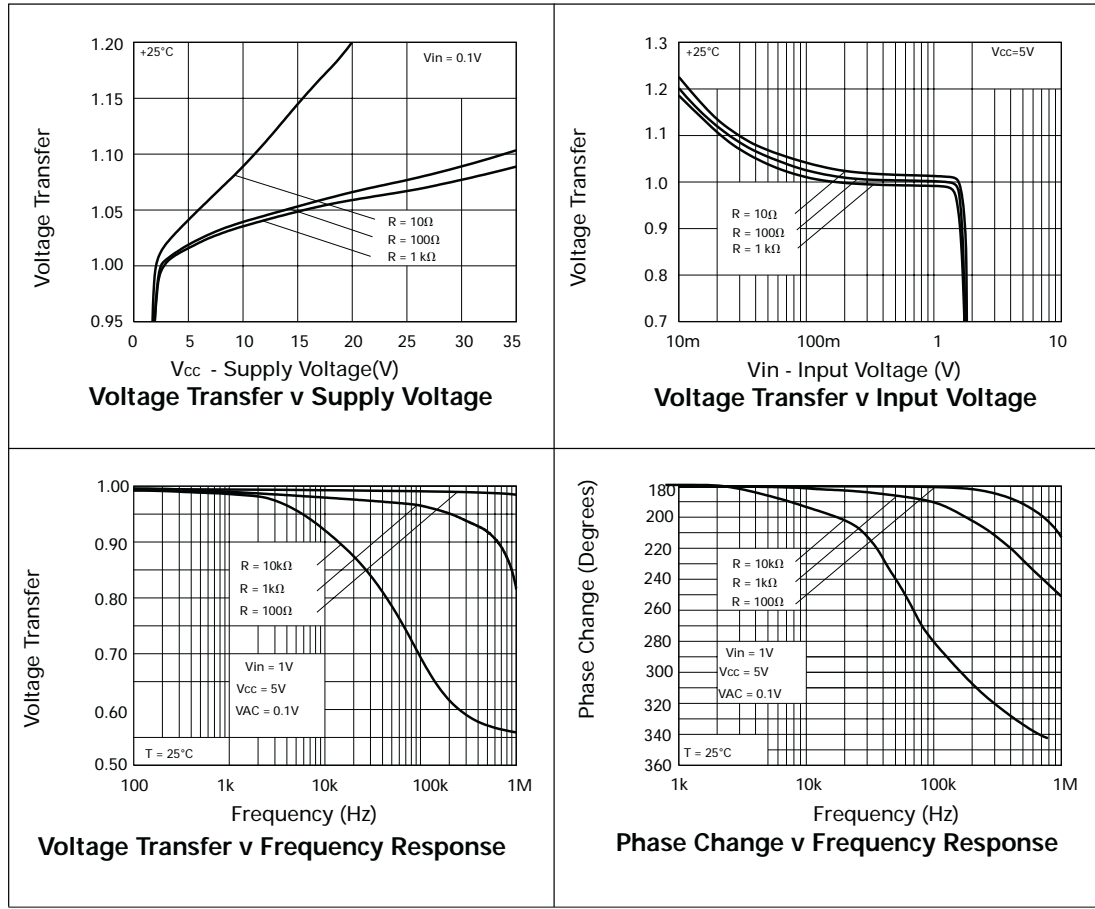
PARAMETER	SYMBOL	VALUE	UNIT
Maximum Operating Voltage	$V_{Y1-X1}$	120	V
Maximum Voltage (E1-E2,E3-E4)	$V_{E-E'}$	10	V
Peak Pulse Current	$I_M$	4	A
Continuous Current (E1-E4,E2-E3)	$I_C$	1	A
Total Power Dissipation at $T_{amb} = 25^\circ\text{C}^*$	$P_{tot}$	2	W
Operating and Storage Temperature Range	$T_J:T_{stg}$	-55 to +150	$^\circ\text{C}$

\* The power which can be dissipated assuming the device is mounted in a typical manner on a PCB with copper equal to 2 inches square.

## ELECTRICAL CHARACTERISTICS (at $T_{amb}=25^\circ\text{C}$ )

Parameter	Symbol	Min	Max	Unit	Conditions
Breakdown Voltage	$BV_{Y1-X1}$	120		V	$I_{Y1}=100\mu\text{A}$
Breakdown Voltage	$BV_{X1-E1}$	-30		V	$I_{X1}=-10\text{mA}$
Breakdown Voltage	$BV_{Y1-E3}$	30		V	$I_{Y1}=10\text{mA}$
Breakdown Voltage	$BV_{E1-Y1}$	-12		V	$I_{E1}=-100\mu\text{A}$
Breakdown Voltage	$BV_{E2-Y1}$	-6		V	$I_{E2}=-100\mu\text{A}$
Breakdown Voltage	$BV_{E3-X1}$	12		V	$I_{E3}=100\mu\text{A}$
Breakdown Voltage	$BV_{E4-X1}$	6		V	$I_{E4}=100\mu\text{A}$
Leakage	$I_{Y1}$		50	nA	$V_{Y1-X1}=100\text{V}$
Leakage	$I_{X1}$		-10	$\mu\text{A}$	$V_{X1-E1}=-30\text{V}, V_{Y1}=V_{E1}$
Leakage	$I_{Y1}$		10	$\mu\text{A}$	$V_{Y1-E3}=30\text{V}, V_{X1}=V_{E3}$
Leakage	$I_{E1}$		-100	nA	$V_{E1-Y1}=-8\text{V}$
Leakage	$I_{E2}$		-100	nA	$V_{E2-Y1}=-4\text{V}$
Leakage	$I_{E3}$		100	nA	$V_{E3-X1}=8\text{V}$
Leakage	$I_{E4}$		100	nA	$V_{E4-X1}=4\text{V}$
Input Voltage	$V_{Y1-E2}$	-1.45	-1.65	V	$I_{Y1}=-1\text{A}$
Input Voltage	$V_{Y1-E3}$	1.45	1.75	V	$I_{Y1}=1\text{A}, V_{X1}=V_{Y1}$
Input Voltage	$V_{X1-E1}$	-1.45	-1.75	V	$I_{X1}=-1\text{A}, V_{X1}=V_{Y1}$
Input Voltage	$V_{X1-E4}$	1.45	1.65	V	$I_{X1}=1\text{A}$
Transfer Characteristic	$V_{OUT}$	0.99	1.01	V	See Fig 1. $V_{CC}=5\text{V}$ $R1=R3=R4=100\Omega, V_{IN}=1\text{V}$
Transfer Characteristic	$V_{OUT}$	1		mV	See Fig 1. $V_{CC}=5\text{V}$ $R1=R3=R4=100\Omega, V_{IN}=5\text{mV}$
Output Zero-Offset Voltage	$V_{OFFSET}$		4	mV	See Fig 2. $V_{CC}=5\text{V}, R_2<1\Omega$ $R1=R3=R4=100\Omega$

TYPICAL CHARACTERISTICS



TEST CIRCUITS

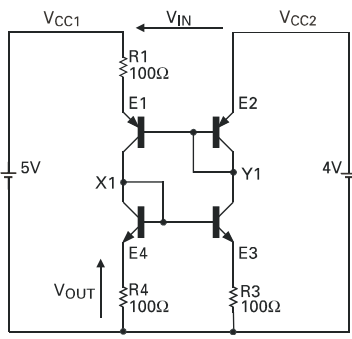


Figure 1  
Transfer Characteristic Test Circuit

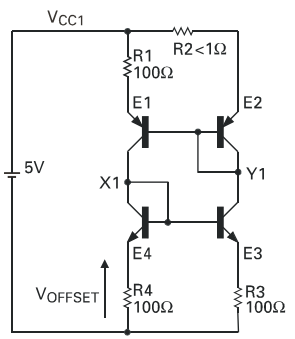
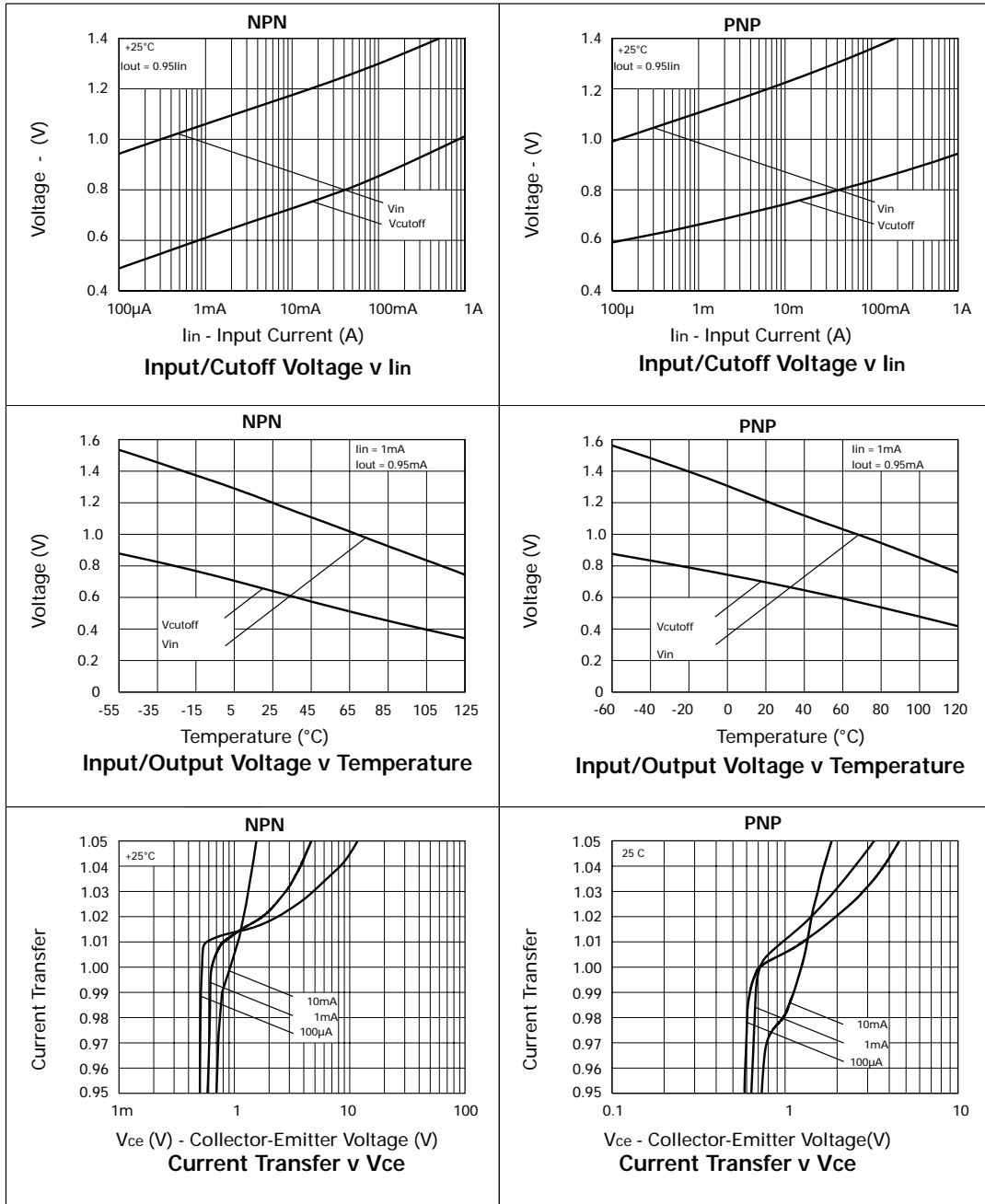


Figure 2  
Output Zero-Offset Voltage Test Circuit

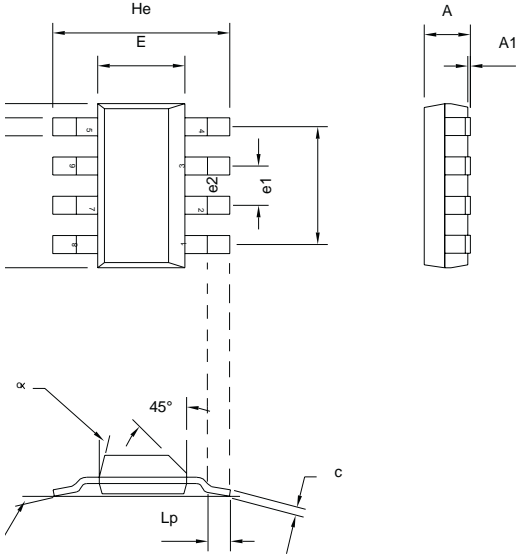
# ZDS1009

## TYPICAL CHARACTERISTICS



# ZDS1009

## PACKAGE DIMENSIONS



DIM	Millimetres			Inches		
	Min	Typ	Max	Min	Typ	Max
A	-	-	1.7	-	-	0.067
A1	0.02	-	0.1	0.0008	-	0.004
b	-	0.7	-	-	0.028	-
c	0.24	-	0.32	0.009	-	0.013
D	6.3	-	6.7	0.248	-	0.264
E	3.3	-	3.7	0.130	-	0.145
e1	-	4.59	-	-	0.180	-
e2	-	1.53	-	-	0.060	-
He	6.7	-	7.3	0.264	-	0.287
Lp	0.9	-	-	0.035	-	-
$\alpha$	-	-	15°	-	-	15°
$\beta$	-	10°	-	-	10°	-

## ORDERING INFORMATION

DEVICE	PARTMARKING
ZDS1009	S1009

**ZETEX** Zetex plc.  
 Fields New Road, Chadderton, Oldham, OL9 8NP, United Kingdom.  
 Telephone: (44)161 622 4422 (Sales), (44)161 622 4444 (General Enquiries)  
 Fax: (44)161 622 4420

Zetex GmbH  
 Streifeldstraße 19  
 D-81673 München  
 Germany  
 Telefon: (49) 89 45 49 49 0  
 Fax: (49) 89 45 49 49 49

Zetex Inc.  
 47 Mall Drive, Unit 4  
 Commack NY 11725  
 USA  
 Telephone: (631) 543-7100  
 Fax: (631) 864-7630

Zetex (Asia) Ltd.  
 3510 Metroplaza, Tower 2  
 Hing Fong Road,  
 Kwai Fong, Hong Kong  
 Telephone: (852) 26100 611  
 Fax: (852) 24250 494



These are supported by  
 agents and distributors in  
 major countries world-wide  
 © Zetex plc 2000  
 Internet <http://www.zetex.com>

This publication is issued to provide outline information only which (unless agreed by the Company in writing) may not be used, applied or reproduced for any purpose or form part of any order or contract or be regarded as a representation relating to the products or services concerned. The Company reserves the right to alter without notice the specification, design, price or conditions of supply of any product or service.



## Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

-  [View ZDS1009TA on WIN SOURCE](#)
-  [Diodes Incorporated Information](#)

## Optimize Your Supply Chain with WIN SOURCE Solutions

-  Global Sourcing Solution
-  Obsolete Management
-  Cost Control Management
-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management